



N-CHANNEL ENHANCEMENT MODE MOSFET

#### **Product Summary**

PPAP and is ideal for use in:

**DC-DC Converters** 

**Body Control Electronics** 

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> max	Ι <sub>D</sub> T <sub>C</sub> = +25°C
20V	550 mΩ @ V <sub>GS</sub> = 4.5V	0.54 mA

This MOSFET is designed to meet the stringent requirements of

Automotive applications. It is qualified to AEC-Q101, supported by a

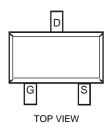
#### **Features and Benefits**

- Low On-Resistance: R<sub>DS(ON)</sub>
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 standards for High Reliability
- PPAP Capable (Note 4)

#### **Mechanical Data**

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.006 grams (Approximate)





Internal Schematic

TOP

### Ordering Information (Note 5)

**Description and Applications** 

**Engine Management Systems** 

Part Number	Case	Packaging
DMN2004WKQ-7	SOT-323	3,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

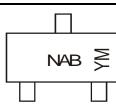
2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product\_compliance\_definitions.html

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**



 $\begin{array}{l} \mathsf{NAB} = \mathsf{Product Type Marking Code} \\ \mathsf{YM} = \mathsf{Date Code Marking} \\ \mathsf{Y or } \overline{\mathsf{Y}} = \mathsf{Year} \ (\mathsf{ex: } \mathsf{D} = 2016) \\ \mathsf{M} = \mathsf{Month} \ (\mathsf{ex: } 9 = \mathsf{September}) \end{array}$ 

#### Date Code Key

Year	201	6	2017		2018	20	19	2020		2021	2	2022
Code	D		E		F	(	G	Н				J
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



## Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Cha	racteristic		Symbol	Value	Units
Drain-Source Voltage			V <sub>DSS</sub>	20	V
Gate-Source Voltage			V <sub>GSS</sub>	±8	V
Drain Current (Note 6)	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +85°C	۱ <sub>D</sub>	540 390	mA
Pulsed Drain Current (Note 7)			IDM	1.5	А

#### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 6)	PD	200	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	625	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

6. Device mounted on FR-4 PCB. Notes:

7. Pulse width  $\leq 10\mu$ S, Duty Cycle  $\leq 1\%$ .

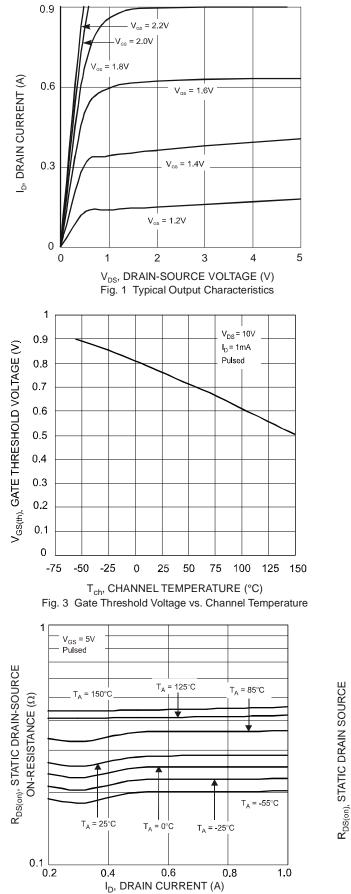
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	20			V	$V_{GS} = 0V, I_D = 10\mu A$	
Zero Gate Voltage Drain Current	IDSS			1	μA	$V_{DS} = 16V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_		±1	μA	$V_{GS} = \pm 4.5 V, V_{DS} = 0 V$	
ON CHARACTERISTICS (Note 8)			•	•		-	
Gate Threshold Voltage	V <sub>GS(th)</sub>	0.5	_	1.0	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
		_	0.4 0.5	0.55 0.70	Ω	$V_{GS} = 4.5V, I_D = 540mA$	
Static Drain-Source On-Resistance	R <sub>DS (ON)</sub>					$V_{GS} = 2.5V, I_D = 500mA$	
			0.7	0.9		$V_{GS} = 1.8V, I_D = 350mA$	
Forward Transfer Admittance	Y <sub>fs</sub>	200		_	ms	V <sub>DS</sub> =10V, I <sub>D</sub> =0.2A	
Diode Forward Voltage (Note 8)	V <sub>SD</sub>	0.5		1.4	V	$V_{GS} = 0V, I_{S} = 115mA$	
DYNAMIC CHARACTERISTICS(Note 9)	DYNAMIC CHARACTERISTICS(Note 9)						
Input Capacitance	Ciss	_	—	150	pF		
Output Capacitance	Coss	_		25	pF	−V <sub>DS</sub> = 16V, V <sub>GS</sub> = 0V −f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_		20	pF		

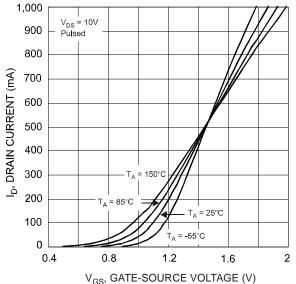
 8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to production testing. Notes:

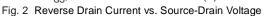


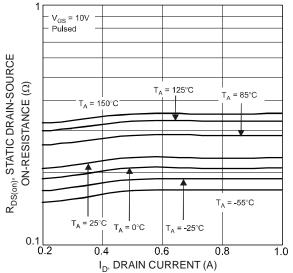
## DMN2004WKQ













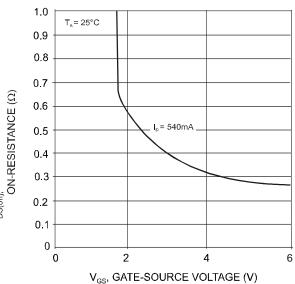
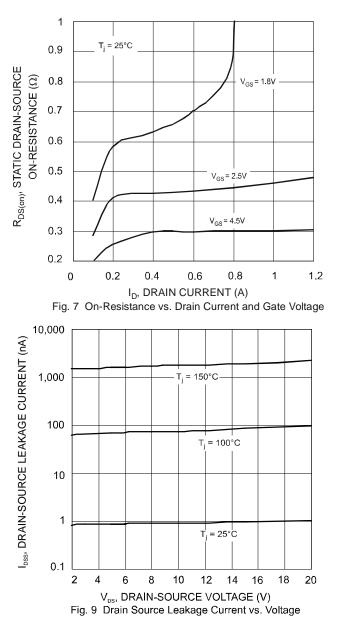
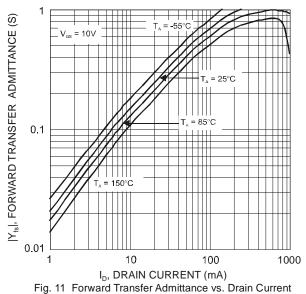


Fig. 6 Static Drain-Source, On-Resistance vs. Gate-Source Voltage









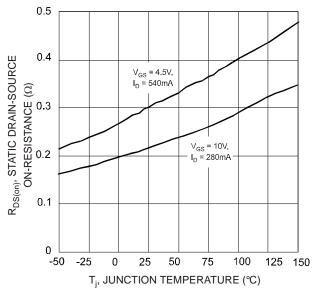
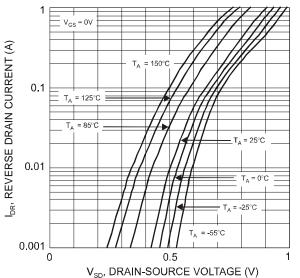
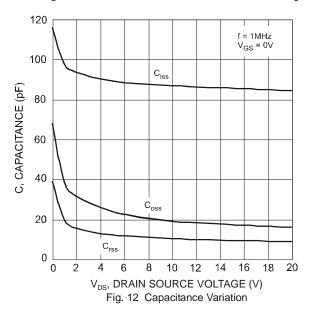


Fig. 8 Static Drain-Source, On-Resistance vs. Temperature



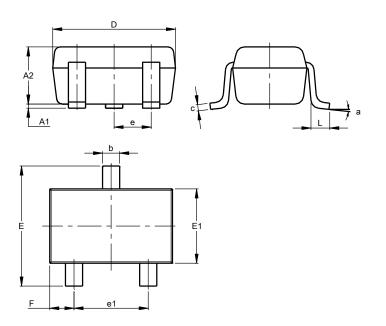






# Package Outline Dimensions

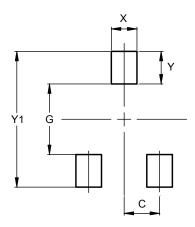
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SOT323							
Dim	Min	Max	Тур					
A1	0.00	0.10	0.05					
A2	0.90	1.00	0.95					
b	0.25	0.40	0.30					
С	0.10	0.18	0.11					
D	1.80	2.20	2.15					
Ε	2.00	2.20	2.10					
E1	1.15	1.35	1.30					
е	C	).650 B	SC					
e1	1.20	1.40	1.30					
F	0.375	0.475	0.425					
L	0.25	0.40	0.30					
а	0°	8°						
All	All Dimensions in mm							

### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.470
Y	0.600
Y1	2.500



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